

CMOS Crystal Oscillator

Features

- Ultra-Low Jitter, Fundamental or 3rd Overtone Crystal Design
- CMOS Output Crystal Oscillator
- Output Frequencies from 32 kHz to 160.000 MHz
- 1.8V, 2.5V, 3.3V, or 5.0V Operation
- Output Disable Feature
- Excellent ±25 ppm Temperature Stability
- -10°C to +70°C, -40°C to +85°C, -40°C to +105°C, -40°C to +125°C, or -55°C to +125°C
 Operating Temperature
- Small, Industry-Standard 7 mm x 5 mm LDFN Package
- Product is Compliant to RoHS Directive and Fully Compatible with Lead-Free Assembly (Excluding Solder-Dipped _SNPB Option)

Applications

- SONET/SDH/DWDM
- Ethernet, GE, SyncE
- Storage Area Networking
- Fibre Channel
- · Digital Video
- Broadband Access
- · Base Stations, Picocells
- Driving A/Ds, D/As, FPGAs
- Test and Measurement
- COTS

Block Diagram



General Description

Microchip's VCC1A crystal oscillator (XO) is a quartz stabilized, square wave generator with a CMOS output. The VCC1A uses a fundamental or 3rd overtone crystal that results in very low jitter performance and uses a monolithic IC that improves reliability and reduces cost.

1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

Storage Temperature (T _S)	–55°C to +125°C
Soldering Temp/Time (T _{1S})	
ESD Rating, Human Body Model (Note 1)	
ESD Rating, Charged Device Model (Note 1)	

† Notice: Stresses in excess of the Absolute Maximum Ratings can permanently damage the device. Functional operation is not implied at these or any other conditions in excess of conditions represented in the operational sections of this data sheet. Exposure to Absolute Maximum Ratings for extended periods may adversely affect device reliability.

Note 1: Although ESD protection circuitry has been designed into the VCC1A, proper precautions should be taken when handling and mounting. Microchip employs a Human Body Model (HBM) and a Charged Device Model (CDM) for ESD susceptibility testing and design protection evaluation. Human Body Model tested to JES22-A115 conditions. Charged Device Model tested to JESD22-C101 conditions.

Parameter	Sym.	Min.	Тур.	Max.	Units	Conditions			
Supply	Supply								
Voltage	V _{DD}	4.5	5.0	5.5	V	Note 1			
Max. Supply Voltage	_	-0.5	_	7.0	V	—			
Max. Voltage E/D	_	-0.5	_	V _{DD} + 0.5	V	—			
			_	5		≤12 MHz			
		_	_	13		12.001 MHz to 20.000 MHz			
Current (Note 2)	I _{DD}	_	_	21	mA	20.001 MHz to 65 MHz			
		_	_	30		65.001 MHz to 100 MHz			
Current, Output Disabled	_	_	_	10	μA	—			
Frequency									
Nominal Frequency	f _{NOM}	0.032	_	100.000	MHz	_			
Stability (Note 3)		_	_	±25					
		_	_	±32					
	_	_	_	±50	- ppm	Ordering Option			
				±100					

ELECTRICAL CHARACTERISTICS, 5V OPTION

- 2: Parameters are tested with the test circuit shown in Figure 1-1. Add ((50 pF 15 pF) x V_{DD} x f_{OUT} (in MHz) x 0.001) mA for the ±50 pF option
- **3:** Includes initial accuracy, operating temperature, supply voltage, shock and vibration (not under operation), and 10 years' aging for ±50 ppm and ±100 ppm options.
- 4: Duty Cycle is measured as ON Time/Period. See Figure 1-2.
- 5: Broadband Period Jitter measured using LeCroy Wavemaster 610Zi, 100K samples.
- 6: Measured using an Agilent E5052 or equivalent at 100 MHz and +25°C.
- **7:** The output is enabled if the Enable/Disable is left open. A 10 kΩ pull-up to V_{DD} is recommended. In disable mode, oscillation stops and the output is high impedance for both Tri-state and Disable mode ordering options.

ELECTRICAL CHARACTERISTICS, 5V OPTION (CONTINUED)

Parameter	Sym.	Min.	Тур.	Max.	Units	Conditions
Outputs		-		•		1
Output Logic Level High	V _{OH}	0.9 x V _{DD}	_	—	V	Note 2
Output Logic Level Low	V _{OL}	_		0.1 x V _{DD}	V	Note 2
Load	I _{OUT}	—	15	_	pF	—
		_	_	30		<1.024 MHz
Output Rise/Fall Time	1 /L	_		8		1.024 MHz to 20 MHz
(Note 2)	t _R /t _F	—	_	5	ns	20.001 MHz to 50.000 MHz
		_	_	3		50.001 MHz to 100 MHz
Output Leakage	ا _Z	_		±10	μA	Output Disabled
Duty Cycle		45	50	55	%	Note 2, Note 4
Period Jitter (Note 5)	Φյ	_	2.4	—	ps	RMS
100 MHz		—	23	_		Peak-to-peak
RMS Jitter (Note 6)	ΦJ	—	65	100	fs	12 kHz to 20 MHz
Enable/Disable						
Output Enable/Disable	V _{IH}	$0.7 \mathrm{x} \mathrm{V_{DD}}$		_	V	Output Enable
(Note 7)	V _{IL}	—	_	0.4	V	Output Disable
Disable Time	t _D	_	_	100	ns	—
Start-Up Time	t _{SU}	_		10	ms	—
		-10	_	70	°C	
		-40	_	85	°C	
Operating Temperature	T _{OP}	-40	_	105	°C	Ordering Option
		-40		125	°C	
		-55	_	125	°C	

Note 1: The power supply should have bypass capacitors as close to the supply and to ground as possible. For example, 0.1 μ F and 0.01 μ F.

2: Parameters are tested with the test circuit shown in Figure 1-1. Add ((50 pF - 15 pF) x V_{DD} x f_{OUT} (in MHz) x 0.001) mA for the ±50 pF option

3: Includes initial accuracy, operating temperature, supply voltage, shock and vibration (not under operation), and 10 years' aging for ±50 ppm and ±100 ppm options.

- 4: Duty Cycle is measured as ON Time/Period. See Figure 1-2.
- 5: Broadband Period Jitter measured using LeCroy Wavemaster 610Zi, 100K samples.
- 6: Measured using an Agilent E5052 or equivalent at 100 MHz and +25°C.
- **7:** The output is enabled if the Enable/Disable is left open. A 10 kΩ pull-up to V_{DD} is recommended. In disable mode, oscillation stops and the output is high impedance for both Tri-state and Disable mode ordering options.

ELECTRICAL CHARACTERISTICS, 3.3V OPTION

Parameter	Sym.	Min.	Тур.	Max.	Units	Conditions
Supply						
Voltage	V _{DD}	2.97	3.3	3.63	V	Note 1
Max. Supply Voltage	_	-0.5	_	7.0	V	_
Max. Voltage E/D	_	-0.5	_	V _{DD} + 0.5	V	_
		_	_	3		≤12 MHz
		_	_	4		12.001 MHz to 20.000 MHz
Current (Note 2)	I _{DD}	_	_	12	mA	20.001 MHz to 65 MHz
		_	_	21		65.001 MHz to 133 MHz
		_	_	27		133.001 MHz to 160 MHz
Current, Output Disabled	_	_	_	10	μA	_
Frequency						·
Nominal Frequency	f _{NOM}	0.032	_	160.000	MHz	_
	_	_	_	±25	ppm	
		_	_	±32		
Stability (Note 3)		_	_	±50		Ordering Option
		_	_	±100		
Outputs						·
Output Logic Level High	V _{OH}	0.9 x V _{DD}	_	_	V	Note 2
Output Logic Level Low	V _{OL}	_	_	0.1 x V _{DD}	V	Note 2
Load	I _{OUT}	_	15	_	pF	_
		_	_	30		<1.024 MHz
Output Rise/Fall Time	1 /I	_	_	8		1.024 MHz to 20 MHz
(Note 2)	t _R /t _F	_	_	5	ns	20.001 MHz to 50.000 MHz
		_	_	3		50.001 MHz to 160 MHz
Output Leakage	Ι _Ζ			±10	μA	Output Disabled
Duty Cycle		45	50	55	%	Note 2, Note 4
Period Jitter (Note 5)	<i>•</i>	_	2.8			RMS
100 MHz	ΦJ	_	25	_	ps	Peak-to-peak
RMS Jitter (Note 6)	ΦJ	_	76	115	fs	12 kHz to 20 MHz

- 2: Parameters are tested with the test circuit shown in Figure 1-1. Add ((50 pF 15 pF) x V_{DD} x f_{OUT} (in MHz) x 0.001) mA for the ±50 pF option
- **3:** Includes initial accuracy, operating temperature, supply voltage, shock and vibration (not under operation), and 10 years' aging for ±50 ppm and ±100 ppm options.
- 4: Duty Cycle is measured as ON Time/Period. See Figure 1-2.
- 5: Broadband Period Jitter measured using LeCroy Wavemaster 610Zi, 100K samples.
- 6: Measured using an Agilent E5052 or equivalent at 100 MHz and +25°C.
- **7:** The output is enabled if the Enable/Disable is left open. A 10 kΩ pull-up to V_{DD} is recommended. In disable mode, oscillation stops and the output is high impedance for both Tri-state and Disable mode ordering options.

ELECTRICAL CHARACTERISTICS, 3.3V OPTION (CONTINUED)

				1	1				
Parameter	Sym.	Min.	Тур.	Max.	Units	Conditions			
Enable/Disable	Enable/Disable								
Output Enable/Disable	V _{IH}	0.7 x V _{DD}		_	V	Output Enable			
(Note 7)	V _{IL}	_		0.4	V	Output Disable			
Disable Time	t _D	_	_	100	ns	-			
Start-Up Time	t _{SU}	_	_	10	ms	_			
		-10	_	70	°C				
		-40	_	85	°C				
Operating Temperature	Т _{ОР}	-40	_	105	°C	Ordering Option			
		-40	_	125	°C				
		-55	_	125	°C]			

- 2: Parameters are tested with the test circuit shown in Figure 1-1. Add ((50 pF 15 pF) x V_{DD} x f_{OUT} (in MHz) x 0.001) mA for the ±50 pF option
- **3:** Includes initial accuracy, operating temperature, supply voltage, shock and vibration (not under operation), and 10 years' aging for ±50 ppm and ±100 ppm options.
- 4: Duty Cycle is measured as ON Time/Period. See Figure 1-2.
- 5: Broadband Period Jitter measured using LeCroy Wavemaster 610Zi, 100K samples.
- 6: Measured using an Agilent E5052 or equivalent at 100 MHz and +25°C.
- **7:** The output is enabled if the Enable/Disable is left open. A 10 kΩ pull-up to V_{DD} is recommended. In disable mode, oscillation stops and the output is high impedance for both Tri-state and Disable mode ordering options.

ELECTRICAL CHARACTERISTICS, 2.5V OPTION

Parameter	Sym.	Min.	Тур.	Max.	Units	Conditions
Supply						-
Voltage	V _{DD}	2.25	2.5	2.75	V	Note 1
Max. Supply Voltage	_	-0.5	_	7.0	V	_
Max. Voltage E/D	_	-0.5	_	V _{DD} + 0.5	V	_
		_	_	2		≤12 MHz
		_	_	3		12.001 MHz to 20 MHz
Current (Note 2)	I _{DD}	_	_	9	mA	20.001 MHz to 65 MHz
		_	_	16		65.001 MHz to 133 MHz
		_	_	23		133.001 MHz to 160 MHz
Current, Output Disabled	_	_	_	10	μA	_
Frequency						
Nominal Frequency	f _{NOM}	0.032	_	160.000	MHz	_
	_	_	_	±25	ppm	
		_	_	±32		
Stability (Note 3)		_		±50		Ordering Option
		_	_	±100		
Outputs						
Output Logic Level High	V _{OH}	0.9 x V _{DD}	_	_	V	Note 2
Output Logic Level Low	V _{OL}	_	_	0.1 x V _{DD}	V	Note 2
Load	I _{OUT}	_	15	_	pF	_
		_	_	30		<1.024 MHz
Output Rise/Fall Time	1 /1	_	_	8		1.024 MHz to 20 MHz
(Note 2)	t _R /t _F	_	_	5	ns	20.001 MHz to 50.000 MHz
		_	_	3		50.001 MHz to 160 MHz
Output Leakage	Ι _Ζ	_		±10	μA	Output Disabled
Duty Cycle	_	45	50	55	%	Note 2, Note 4
Period Jitter (Note 5)		_	2.8	_		RMS
100 MHz	ΦJ	_	26	_	ps	Peak-to-peak
RMS Jitter (Note 6)	ΦJ	_	97	145	fs	12 kHz to 20 MHz

- 2: Parameters are tested with the test circuit shown in Figure 1-1. Add ((50 pF 15 pF) x V_{DD} x f_{OUT} (in MHz) x 0.001) mA for the ±50 pF option
- **3:** Includes initial accuracy, operating temperature, supply voltage, shock and vibration (not under operation), and 10 years' aging for ±50 ppm and ±100 ppm options.
- 4: Duty Cycle is measured as ON Time/Period. See Figure 1-2.
- 5: Broadband Period Jitter measured using LeCroy Wavemaster 610Zi, 100K samples.
- 6: Measured using an Agilent E5052 or equivalent at 100 MHz and +25°C.
- **7:** The output is enabled if the Enable/Disable is left open. A 10 kΩ pull-up to V_{DD} is recommended. In disable mode, oscillation stops and the output is high impedance for both Tri-state and Disable mode ordering options.

ELECTRICAL CHARACTERISTICS, 2.5V OPTION (CONTINUED)

				1	1				
Parameter	Sym.	Min.	Тур.	Max.	Units	Conditions			
Enable/Disable	Enable/Disable								
Output Enable/Disable	V _{IH}	0.7 x V _{DD}		_	V	Output Enable			
(Note 7)	V _{IL}	_		0.4	V	Output Disable			
Disable Time	t _D	_	_	100	ns	-			
Start-Up Time	t _{SU}	_	_	10	ms	_			
		-10	_	70	°C				
		-40	_	85	°C				
Operating Temperature	Т _{ОР}	-40	_	105	°C	Ordering Option			
		-40	_	125	°C				
		-55	_	125	°C]			

- 2: Parameters are tested with the test circuit shown in Figure 1-1. Add ((50 pF 15 pF) x V_{DD} x f_{OUT} (in MHz) x 0.001) mA for the ±50 pF option
- **3:** Includes initial accuracy, operating temperature, supply voltage, shock and vibration (not under operation), and 10 years' aging for ±50 ppm and ±100 ppm options.
- 4: Duty Cycle is measured as ON Time/Period. See Figure 1-2.
- 5: Broadband Period Jitter measured using LeCroy Wavemaster 610Zi, 100K samples.
- 6: Measured using an Agilent E5052 or equivalent at 100 MHz and +25°C.
- **7:** The output is enabled if the Enable/Disable is left open. A 10 kΩ pull-up to V_{DD} is recommended. In disable mode, oscillation stops and the output is high impedance for both Tri-state and Disable mode ordering options.

ELECTRICAL CHARACTERISTICS, 1.8V OPTION

Parameter	Sym.	Min.	Тур.	Max.	Units	Conditions
Supply				•		-
Voltage	V _{DD}	1.71	1.8	1.89	V	Note 1
Max. Supply Voltage	_	-0.5	_	7.0	V	_
Max. Voltage E/D	_	-0.5	_	V _{DD} + 0.5	V	_
		_	_	2		≤12 MHz
			_	3		12.001 MHz to 20 MHz
Current (Note 2)	I _{DD}			7	mA	20.001 MHz to 65 MHz
			_	13		65.001 MHz to 133 MHz
				19		133.001 MHz to 160 MHz
Current, Output Disabled	_	_		10	μA	_
Frequency						
Nominal Frequency	f _{NOM}	0.032	_	160.000	MHz	_
	_	_	_	±25	ppm	
		_	_	±32		
Stability (Note 3)		_	_	±50		Ordering Option
				±100		
Outputs						
Output Logic Level High	V _{OH}	0.9 x V _{DD}	_	_	V	Note 2
Output Logic Level Low	V _{OL}	_	_	0.1 x V _{DD}	V	Note 2
Load	I _{OUT}	_	15	_	pF	_
		_	_	30		<1.024 MHz
Output Rise/Fall Time	1 /1		_	8		1.024 MHz to 20 MHz
(Note 2)	t _R /t _F	_	_	5	ns	20.001 MHz to 50.000 MHz
		_	_	3		50.001 MHz to 100 MHz
Output Leakage	Ι _Ζ			±10	μA	Output Disabled
Duty Cycle	_	45	50	55	%	Note 2, Note 4
Period Jitter (Note 5)		_	3.4	—		RMS
100 MHz	ΦJ	_	33	—	ps	Peak-to-peak
RMS Jitter (Note 6)	ΦJ	_	212	320	fs	12 kHz to 20 MHz

- 2: Parameters are tested with the test circuit shown in Figure 1-1. Add ((50 pF 15 pF) x V_{DD} x f_{OUT} (in MHz) x 0.001) mA for the ±50 pF option
- **3:** Includes initial accuracy, operating temperature, supply voltage, shock and vibration (not under operation), and 10 years' aging for ±50 ppm and ±100 ppm options.
- 4: Duty Cycle is measured as ON Time/Period. See Figure 1-2.
- 5: Broadband Period Jitter measured using LeCroy Wavemaster 610Zi, 100K samples.
- 6: Measured using an Agilent E5052 or equivalent at 100 MHz and +25°C.
- **7:** The output is enabled if the Enable/Disable is left open. A 10 kΩ pull-up to V_{DD} is recommended. In disable mode, oscillation stops and the output is high impedance for both Tri-state and Disable mode ordering options.

ELECTRICAL CHARACTERISTICS, 1.8V OPTION (CONTINUED)

Parameter	Sym.	Min.	Тур.	Max.	Units	Conditions			
Enable/Disable	Enable/Disable								
Output Enable/Disable	V _{IH}	0.7 x V _{DD}		_	V	Output Enable			
(Note 7)	V _{IL}	_		0.4	V	Output Disable			
Disable Time	t _D	_	_	100	ns	-			
Start-Up Time	t _{SU}	_	_	10	ms	_			
		-10	_	70	°C				
		-40	_	85	°C				
Operating Temperature	T _{OP}	-40	_	105	°C	Ordering Option			
		-40	_	125	°C				
		-55	_	125	°C]			

Note 1: The power supply should have bypass capacitors as close to the supply and to ground as possible. For example, 0.1 μ F and 0.01 μ F.

- 2: Parameters are tested with the test circuit shown in Figure 1-1. Add ((50 pF 15 pF) x V_{DD} x f_{OUT} (in MHz) x 0.001) mA for the ±50 pF option
- **3:** Includes initial accuracy, operating temperature, supply voltage, shock and vibration (not under operation), and 10 years' aging for ±50 ppm and ±100 ppm options.
- 4: Duty Cycle is measured as ON Time/Period. See Figure 1-2.
- 5: Broadband Period Jitter measured using LeCroy Wavemaster 610Zi, 100K samples.
- 6: Measured using an Agilent E5052 or equivalent at 100 MHz and +25°C.
- **7:** The output is enabled if the Enable/Disable is left open. A 10 kΩ pull-up to V_{DD} is recommended. In disable mode, oscillation stops and the output is high impedance for both Tri-state and Disable mode ordering options.





Test Circuit.



2.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 2-1.

TABLE 2-1:PIN FUNCTION TABLE

Pin Number	Pin Name	Description			
1	E/D	Enable/Disable			
2	GND	Case and Electrical Ground			
3	Output	Output			
4	V _{DD}	Power Supply Voltage			

TABLE 2-2: ENABLE/DISABLE FUNCTION

E/D Pin	Output
High	Clock Output
Open	Clock Output
Low	High Impedance

3.0 RELIABILITY

Microchip qualification includes aging at various extreme temperatures, shock and vibration, temperature cycling, and IR reflow simulation. The VCC1A family is capable of meeting the following qualification tests.

Parameter	Conditions
Mechanical Shock	MIL-STD-883, Method 2002
Mechanical Vibration	MIL-STD-883, Method 2007
Temperature Cycle	MIL-STD-883, Method 1010
Solderability	MIL-STD-883, Method 2003
Gross and Fine Leak	MIL-STD-883, Method 1014
Resistance to Solvents	MIL-STD-883, Method 2015
Moisture Sensitivity Level	MSL 1
Contact Pads	Gold (0.3 µm min. to 1.0 µm max.) over Nickel
Contact Pads, _SNPB Option	Tinned using solder alloy SN63Pb37 in accordance with J-STD-006
Weight	178 mg

TABLE 3-1: ENVIRONMENTAL COMPLIANCE

4.0 IR REFLOW

The VCC1A is qualified to meet the JEDEC standard for Pb-Free assembly. The temperatures and time intervals listed are based on the Pb-Free small body requirements. The VCC1A device is hermetically sealed, so an aqueous wash is not an issue. Note, devices that have been solder dipped (_SNPB option) will not be Pb-Free.



Symbol	Minimum	Maximum	Conditions		
T _{S(1)}	150°C	200°C	Pb-Free		
T _{S(2)}	100°C	150°C	_SNPB Option		
t _{S(1)}	60 sec.	180 sec.	Pb-Free		
t _{S(2)}	60 sec.	120 sec.	_SNPB Option		
t _{l(1)}	60 sec.	150 sec.	Pb-Free		
t _{l(2)}	60 sec.	150 sec.	_SNPB Option		
T _{p(1)}	245°C	260°C	Pb-Free		
T _{p(2)}	225°C	240°C	_SNPB Option		

5.0 TAPE AND REEL

Tape Dimensions (mm)				Reel Dimensions (mm)									
Dimension	W	F	Do	Ро	P1	Α	В	С	D	Ν	W1	W2	# per
Tolerance	Тур	Тур	Тур	Тур	Тур	Тур	Тур	Тур	Тур	Тур	Тур	Max	Reel
VCC1A	16	7.5	1.5	4	8	180	2	13	21	60	17	21	1000





6.0 PACKAGING INFORMATION

4-Lead 7.0 mm x 5.0 mm LDFN Package Outline and Recommended Land Pattern



NOTES:

APPENDIX A: REVISION HISTORY

Revision A (May 2022)

- Converted Vectron document VCC1A to Microchip data sheet template DS20006675A.
- Minor grammatical text changes throughout.

Revision B (March 2023)

- Added two new stability options (P and R) to the Product Identification System section.
- Corrected various values in Table 4-1.
- Added –55°C to +125°C temperature option throughout document.
- Updated frequency capability throughout document.

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

Device		- <u>X</u>	<u>X</u>	<u>×</u>	- <u>XXMXXXXXXX</u>	<u>XX</u>		
Part No.		Power Supply	Electrical Options	Stability	Frequency	Packaging		
Device: Power Supply:	A = 5.0 VDC, 15 pF B = 3.3VDC, 15 pF C = 3.0VDC, 15 pF wer Supply: E = 5.0VDC, 50 pF F = 3.3VDC, 50 pF G = 2.5VDC, 15 pF		F F F F F F	Examples: a) VCC1A-A3F-24M5760000TR: VCC1A, 5.0VDC, 15 pF, Tri-State 45%/! Duty Cycle, ±25 ppm over -40°C to +85 24.576 MHz, 1000/Reel b) VCC1A-G3A-38M4000000: VCC1A, 2.5VDC, 15 pF, Tri-State 45%/! Duty Cycle, ±100 ppm over -10°C to +7 38.400 MHz, Cut Tape				
Electrical Options:	H = 3 =	1.8VDC, 15 p Tri-State 45%	F /55% Duty Cycle (Note 1)	c) VC(C1A-C3V-65M2500000_SNPB VCC1A, 3.0VDC, 15 pF Duty Cycle, ±100 ppm c 65.250 MHz, Tin Lead S	, Tri-State 45%/55% over –40°C to +125°		
Stability:	A = B = C = E = F = F = F = R =	±50 ppm over ±100 ppm over ±50 ppm over ±25 ppm over ±25 ppm over ±32 ppm over ±32 ppm over ±100 ppm over	er -10°C to +70°C -10°C to +70°C -40°C to +85°C -40°C to +85°C -10°C to +70°C -40°C to +85°C -10°C to +70°C -40°C to +85°C -40°C to +85°C -55°C to +125°C -55°C to +125°C	e) VC	C1A-E3R-22M2500000TR: VCC1A, 5.0VDC, 50 pF Duty Cycle, ±50 ppm ov 22.250 MHz, 1000/Reel C1A-F3P-66M6000000: VCC1A, 3.3VDC, 50 pF Duty Cycle, ±100 ppm c 66.600 MHz, Cut Tape	er –55°C to +125°C ; Tri-State 45%/55% ;ver –55°C to +125°		
Fraguancy		±100 ppm ove ±100 ppm ove xx=Frequency	er –40°C to +105°C er –40°C to +125°C in MHz		C1A-B3D-42M0000000_SNPB VCC1A, 3.3VDC, 15 pF Duty Cycle, ±50 ppm ov 42.000 MHz, Tin Lead S	, Tri-State 45%/55% /er –40°C to +85°C Solder Dipped		
Frequency: Packaging:	xxKxxxxx TR = <blank>=</blank>	xx=Frequency i 1,000/Reel Cut Tape/ non Tin Lead Sold	n kHz -TR quantities	Note 1	 Tape and Reel identifier only catalog part number descrip used for ordering purposes the device package. Check Sales Office for package av and Reel option. 	tion. This identifier is and is not printed on with your Microchip		

Note 1: The following codes are not recommended for new designs:

- 0: No tri-state, 40%/60% duty cycle
- 1: Tri-state, 40%/60% duty cycle
- 2: No tri-state, 45%/55% duty cycle
- 5: Enable, 40%/60% duty cycle
- 6: Enable, 45%/55% duty cycle.

Please note that not all combination of options are available. Other specifications may be available upon request. 50 pF load option is available at 3.3V and 5.0V, <60 MHz.

TABLE 1: **20 PPM STABILITY ORDERING INFORMATION**

VCC1A-10	05-xxMxxxxxxx = ±20 ppm over –10°C to +70°C, 5.0VDC, 45%/55% duty cycle, 15 pF load.
VCC1A-10	$03-xxMxxxxxxx = \pm 20$ ppm over -10° C to $+70^{\circ}$ C, 3.3 VDC, $45\%/55\%$ duty cycle, 15 pF load.
VCC1A-11	8-xxMxxxxxxx = ±20 ppm over –10°C to +70°C, 2.5VDC, 45%/55% duty cycle, 15 pF load.
VCC1A-11	9-xxMxxxxxxx = ±20 ppm over –10°C to +70°C, 1.8VDC, 45%/55% duty cycle, 15 pF load.
Note:	The Packaging ontions from the section above also apply to the 20 ppm version listed here

The Packaging options from the section above also apply to the 20 ppm version listed here. Note:

NOTES:

Note the following details of the code protection feature on Microchip products:

- Microchip products meet the specifications contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is secure when used in the intended manner, within operating specifications, and under normal conditions.
- Microchip values and aggressively protects its intellectual property rights. Attempts to breach the code protection features of Microchip product is strictly prohibited and may violate the Digital Millennium Copyright Act.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of its code. Code protection does not
 mean that we are guaranteeing the product is "unbreakable" Code protection is constantly evolving. Microchip is committed to
 continuously improving the code protection features of our products.

This publication and the information herein may be used only with Microchip products, including to design, test, and integrate Microchip products with your application. Use of this information in any other manner violates these terms. Information regarding device applications is provided only for your convenience and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications. Contact your local Microchip sales office for additional support or, obtain additional support at https:// www.microchip.com/en-us/support/design-help/client-supportservices.

THIS INFORMATION IS PROVIDED BY MICROCHIP "AS IS". MICROCHIP MAKES NO REPRESENTATIONS OR WAR-RANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY OR OTHERWISE, RELATED TO THE INFORMATION INCLUDING BUT NOT LIMITED TO ANY IMPLIED WARRANTIES OF NON-INFRINGEMENT, MERCHANTABILITY, AND FITNESS FOR A PARTICULAR PURPOSE, OR WARRANTIES RELATED TO ITS CONDITION, QUALITY, OR PERFORMANCE.

IN NO EVENT WILL MICROCHIP BE LIABLE FOR ANY INDI-RECT, SPECIAL, PUNITIVE, INCIDENTAL, OR CONSE-QUENTIAL LOSS, DAMAGE, COST, OR EXPENSE OF ANY KIND WHATSOEVER RELATED TO THE INFORMATION OR ITS USE, HOWEVER CAUSED, EVEN IF MICROCHIP HAS BEEN ADVISED OF THE POSSIBILITY OR THE DAMAGES ARE FORESEEABLE. TO THE FULLEST EXTENT ALLOWED BY LAW, MICROCHIP'S TOTAL LIABILITY ON ALL CLAIMS IN ANY WAY RELATED TO THE INFORMATION OR ITS USE WILL NOT EXCEED THE AMOUNT OF FEES, IF ANY, THAT YOU HAVE PAID DIRECTLY TO MICROCHIP FOR THE INFORMATION.

Use of Microchip devices in life support and/or safety applications is entirely at the buyer's risk, and the buyer agrees to defend, indemnify and hold harmless Microchip from any and all damages, claims, suits, or expenses resulting from such use. No licenses are conveyed, implicitly or otherwise, under any Microchip intellectual property rights unless otherwise stated.

Trademarks

The Microchip name and logo, the Microchip logo, Adaptec, AVR, AVR logo, AVR Freaks, BesTime, BitCloud, CryptoMemory, CryptoRF, dsPIC, flexPWR, HELDO, IGLOO, JukeBlox, KeeLoq, Kleer, LANCheck, LinkMD, maXStylus, maXTouch, MediaLB, megaAVR, Microsemi, Microsemi logo, MOST, MOST logo, MPLAB, OptoLyzer, PIC, picoPower, PICSTART, PIC32 logo, PolarFire, Prochip Designer, QTouch, SAM-BA, SenGenuity, SpyNIC, SST, SST Logo, SuperFlash, Symmetricom, SyncServer, Tachyon, TimeSource, tinyAVR, UNI/O, Vectron, and XMEGA are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

AgileSwitch, APT, ClockWorks, The Embedded Control Solutions Company, EtherSynch, Flashtec, Hyper Speed Control, HyperLight Load, Libero, motorBench, mTouch, Powermite 3, Precision Edge, ProASIC, ProASIC Plus, ProASIC Plus logo, Quiet- Wire, SmartFusion, SyncWorld, Temux, TimeCesium, TimeHub, TimePictra, TimeProvider, TrueTime, and ZL are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Adjacent Key Suppression, AKS, Analog-for-the-Digital Age, Any Capacitor, AnyIn, AnyOut, Augmented Switching, BlueSky, BodyCom, Clockstudio, CodeGuard, CryptoAuthentication, CryptoAutomotive, CryptoCompanion, CryptoController, dsPICDEM, dsPICDEM.net, Dynamic Average Matching, DAM, ECAN, Espresso T1S, EtherGREEN, GridTime, IdealBridge, In-Circuit Serial Programming, ICSP, INICnet, Intelligent Paralleling, IntelliMOS, Inter-Chip Connectivity, JitterBlocker, Knob-on-Display, KoD, maxCrypto, maxView, memBrain, Mindi, MiWi, MPASM, MPF, MPLAB Certified logo, MPLIB, MPLINK, MultiTRAK, NetDetach, Omniscient Code Generation, PICDEM, PICDEM.net, PICkit, PICtail, PowerSmart, PureSilicon, QMatrix, REAL ICE, Ripple Blocker, RTAX, RTG4, SAM-ICE, Serial Quad I/O, simpleMAP, SimpliPHY, SmartBuffer, SmartHLS, SMART-I.S., storClad, SQI, SuperSwitcher, SuperSwitcher II, Switchtec, SynchroPHY, Total Endurance, Trusted Time, TSHARC, USBCheck, VariSense, VectorBlox, VeriPHY, ViewSpan, WiperLock, XpressConnect, and ZENA are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries

SQTP is a service mark of Microchip Technology Incorporated in the U.S.A.

The Adaptec logo, Frequency on Demand, Silicon Storage Technology, and Symmcom are registered trademarks of Microchip Technology Inc. in other countries.

GestIC is a registered trademark of Microchip Technology Germany II GmbH & Co. KG, a subsidiary of Microchip Technology Inc., in other countries.

All other trademarks mentioned herein are property of their respective companies.

 $\ensuremath{\textcircled{\text{C}}}$ 2023, Microchip Technology Incorporated and its subsidiaries.

All Rights Reserved.

ISBN: 978-1-6683-2248-2

For information regarding Microchip's Quality Management Systems, please visit www.microchip.com/quality.



Worldwide Sales and Service

AMERICAS

Corporate Office 2355 West Chandler Blvd. Chandler, AZ 85224-6199 Tel: 480-792-7200 Fax: 480-792-7277 Technical Support: http://www.microchip.com/ support

Web Address: www.microchip.com

Atlanta Duluth, GA Tel: 678-957-9614 Fax: 678-957-1455

Austin, TX Tel: 512-257-3370

Boston Westborough, MA Tel: 774-760-0087 Fax: 774-760-0088

Chicago Itasca, IL Tel: 630-285-0071 Fax: 630-285-0075

Dallas Addison, TX Tel: 972-818-7423 Fax: 972-818-2924

Detroit Novi, MI Tel: 248-848-4000

Houston, TX Tel: 281-894-5983

Indianapolis Noblesville, IN Tel: 317-773-8323 Fax: 317-773-5453 Tel: 317-536-2380

Los Angeles Mission Viejo, CA Tel: 949-462-9523 Fax: 949-462-9608 Tel: 951-273-7800

Raleigh, NC Tel: 919-844-7510

New York, NY Tel: 631-435-6000

San Jose, CA Tel: 408-735-9110 Tel: 408-436-4270

Canada - Toronto Tel: 905-695-1980 Fax: 905-695-2078

ASIA/PACIFIC

Australia - Sydney Tel: 61-2-9868-6733

China - Beijing Tel: 86-10-8569-7000 China - Chengdu

Tel: 86-28-8665-5511 China - Chongqing Tel: 86-23-8980-9588

China - Dongguan Tel: 86-769-8702-9880

China - Guangzhou Tel: 86-20-8755-8029

China - Hangzhou Tel: 86-571-8792-8115

China - Hong Kong SAR Tel: 852-2943-5100

China - Nanjing Tel: 86-25-8473-2460

China - Qingdao Tel: 86-532-8502-7355

China - Shanghai Tel: 86-21-3326-8000

China - Shenyang Tel: 86-24-2334-2829

China - Shenzhen Tel: 86-755-8864-2200

China - Suzhou Tel: 86-186-6233-1526

China - Wuhan Tel: 86-27-5980-5300

China - Xian Tel: 86-29-8833-7252

China - Xiamen Tel: 86-592-2388138 China - Zhuhai

Tel: 86-756-3210040

ASIA/PACIFIC

India - Bangalore Tel: 91-80-3090-4444

India - New Delhi Tel: 91-11-4160-8631 India - Pune

Tel: 91-20-4121-0141

Japan - Osaka Tel: 81-6-6152-7160

Japan - Tokyo Tel: 81-3-6880- 3770

Korea - Daegu Tel: 82-53-744-4301

Korea - Seoul Tel: 82-2-554-7200

Malaysia - Kuala Lumpur Tel: 60-3-7651-7906

Malaysia - Penang Tel: 60-4-227-8870

Philippines - Manila Tel: 63-2-634-9065

Singapore Tel: 65-6334-8870

Taiwan - Hsin Chu

Tel: 886-3-577-8366 Taiwan - Kaohsiung Tel: 886-7-213-7830

Taiwan - Taipei Tel: 886-2-2508-8600

Thailand - Bangkok Tel: 66-2-694-1351

Vietnam - Ho Chi Minh Tel: 84-28-5448-2100

Tel: 39-049-7625286

Netherlands - Drunen Tel: 31-416-690399 Fax: 31-416-690340

EUROPE

Austria - Wels

Tel: 43-7242-2244-39

Tel: 45-4485-5910

Fax: 45-4485-2829

Tel: 358-9-4520-820

Tel: 33-1-69-53-63-20

Fax: 33-1-69-30-90-79

Germany - Garching

Tel: 49-2129-3766400

Germany - Heilbronn

Germany - Karlsruhe

Tel: 49-7131-72400

Tel: 49-721-625370

Germany - Munich

Tel: 49-89-627-144-0

Fax: 49-89-627-144-44

Germany - Rosenheim

Tel: 49-8031-354-560

Israel - Ra'anana

Italy - Milan

Italy - Padova

Tel: 972-9-744-7705

Tel: 39-0331-742611

Fax: 39-0331-466781

Tel: 49-8931-9700

Germany - Haan

Finland - Espoo

France - Paris

Fax: 43-7242-2244-393

Denmark - Copenhagen

Norway - Trondheim Tel: 47-7288-4388

Poland - Warsaw Tel: 48-22-3325737

Romania - Bucharest Tel: 40-21-407-87-50

Spain - Madrid Tel: 34-91-708-08-90 Fax: 34-91-708-08-91

Sweden - Gothenberg Tel: 46-31-704-60-40

Sweden - Stockholm Tel: 46-8-5090-4654

UK - Wokingham Tel: 44-118-921-5800 Fax: 44-118-921-5820